

LC 3 mm (T1) LED, Diffused Low Current LED

LS 3369, LY 3369, LG 3369



Besondere Merkmale

- **Gehäusotyp:** eingefärbtes, diffuses 3 mm (T1) Gehäuse
- **Besonderheit des Bauteils:** hohe Lichtstärke bei kleinen Strömen; Lötspieße mit Aufsetzebene
- **Wellenlänge:** 628 nm (super-rot), 587 nm (gelb), 570 nm (grün)
- **Abstrahlwinkel:** 60°
- **Technologie:** GaAlP
- **optischer Wirkungsgrad:** 2 lm/W
- **Gruppierungsparameter:** Lichtstärke
- **Lötmethode:** Wellenlöten (TTW)
- **Verpackung:** Schüttgut, gegurtet lieferbar

Anwendungen

- optischer Indikator
- Hinterleuchtung (LCD, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u.ä.)

Features

- **package:** colored, diffused 3 mm (T1) package
- **feature of the device:** high luminous intensity at low currents; solder leads with stand-off
- **wavelength:** 628 nm (super-red), 587 nm (yellow), 570 nm (green)
- **viewing angle:** 60°
- **technology:** GaAlP
- **optical efficiency:** 2 lm/W
- **grouping parameter:** luminous flux
- **soldering methods:** TTW soldering
- **packing:** bulk, available taped on reel

Applications

- optical indicators
- backlighting (LCD, switches, keys, displays, illuminated advertising, general lighting)
- interior automotive lighting (e.g. dashboard backlighting, etc.)

Typ Type	Emissionsfarbe Color of Emission	Gehäusefarbe Color of Package	Lichtstärke Luminous Intensity $I_F = 2 \text{ mA}$ $I_V \text{ (mcd)}$	Bestellnummer Ordering Code
LS 3369-EH LS 3369-GK	super-red	red diffused	0.71 ... 4.50 1.80 ... 11.2	Q62703Q1748 Q62703Q3821
LY 3369-EH LY 3369-FJ	yellow	yellow diffused	0.71 ... 4.50 1.12 ... 7.10	Q62703Q1749 Q62703Q3822
LG 3369-EH LG 3369-FJ	green	green diffused	0.71 ... 4.50 1.12 ... 7.10	Q62703Q1750 Q62703Q3823

Anm.: Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe oder mindestens zwei Einzelgruppen.

In einer Verpackungseinheit / Gurt ist immer nur eine Helligkeitsgruppe enthalten.

Die technologiebedingte Helligkeits-Streuung der heutigen LED-Herstellprozesse über einen längeren Fertigungszeitraum (Halbleitermaterial - Chipherstellung - Montageprozess) erlaubt keine Zusage einer einzelnen Helligkeitsgruppe. Daher müssen mindestens zwei Helligkeitsgruppen vorgesehen werden!

Note: The standard shipping format for serial types includes a lower or upper family group or at least two individual groups.

No packing unit / tape ever contains more than one luminous intensity group.

Luminosity variations caused by the technology used in current LED manufacturing processes over a protracted manufacturing period (semiconductor material - chip fabrication - assembly process) mean that it is not possible to assign LEDs to a single luminous intensity group. For this reason at least two luminous intensity groups must be provided!

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebstemperatur Operating temperature range	T_{op}	– 55 ... + 100	°C
Lagertemperatur Storage temperature range	T_{stg}	– 55 ... + 100	°C
Sperrschichttemperatur Junction temperature	T_j	+ 100	°C
Durchlassstrom Forward current ($T_A=25^\circ\text{C}$)	I_F	7.5	mA
Stoßstrom Surge current $t \leq 10 \mu\text{s}$, $D = 0.005$, $T_A=25^\circ\text{C}$	I_{FM}	0.15	A
Sperrspannung ¹⁾ Reverse voltage ($T_A=25^\circ\text{C}$)	V_R	12	V
Leistungsaufnahme Power consumption ($T_A=25^\circ\text{C}$)	P_{tot}	20	mW
Wärmewiderstand ²⁾ Thermal resistance Sperrschicht/Umgebung ³⁾ Junction/ambient ³⁾	$R_{th JA}$	400	K/W
Sperrschicht/Lötpad Junction/solder point Minimale Beinchenlänge Minimum lead length	$R_{th JS}$	180	K/W

¹⁾ für kurzzeitigen Betrieb geeignet / suitable for short term application

²⁾ R_{th} erhöht sich um 13 K/W pro mm Beinchenlänge.
Each additional 1 mm of lead length increases R_{th} by 13 K/W.

³⁾ Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$)
mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)

Kennwerte ($T_A = 25\text{ °C}$)**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LS	LY	LG	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 2\text{ mA}$	λ_{peak}	635	586	572	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength $I_F = 2\text{ mA}$	λ_{dom}	628	587	570	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 2\text{ mA}$	$\Delta\lambda$	45	45	25	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	60	60	60	Grad deg.
Durchlassspannung ²⁾ (typ.) Forward voltage (max.) $I_F = 2\text{ mA}$	V_F V_F	1.8 2.5	2.0 2.6	1.9 2.5	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 12\text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 2\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.11	0.10	0.11	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 2\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.07	0.07	0.07	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 2\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 2.0	- 1.6	- 1.9	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 2\text{ mA}$	η_{opt}	2	2	2	lm/W

¹⁾ Wellenlängen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelengths are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Spannungswerte werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Helligkeits-Gruppierungsschema Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_v (mcd)
E	0.71 ... 1.12
F	1.12 ... 1.80
G	1.80 ... 2.80
H	2.80 ... 4.50
J	4.50 ... 7.10
K	7.10 ... 11.20

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Gruppenbezeichnung auf Etikett Group Name on Label

Beispiel: J
Example: J

Lichtgruppe Luminous Intensity Group

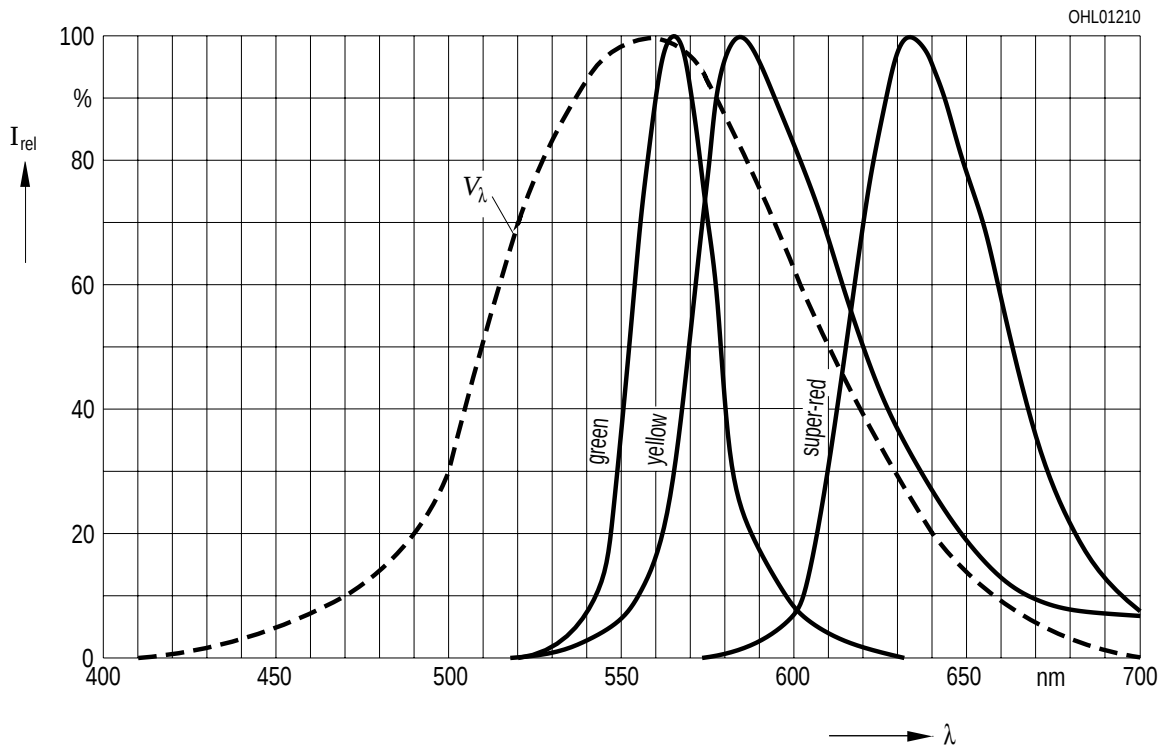
J

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 2\text{ mA}$

Relative Spectral Emission

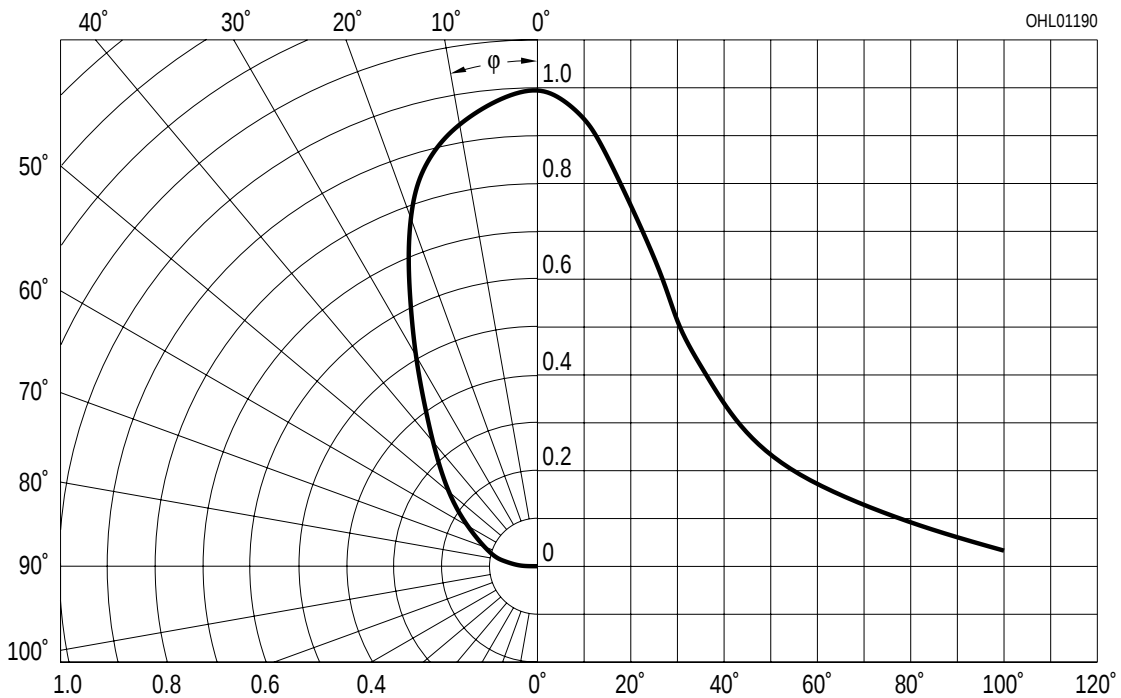
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

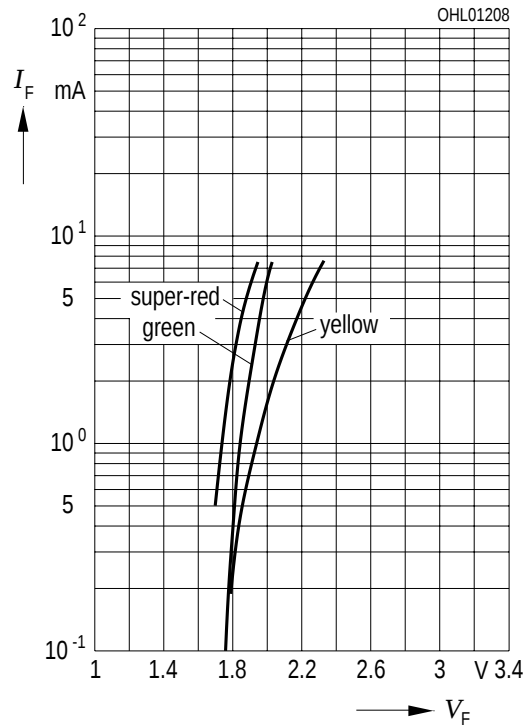
Radiation Characteristic



Durchlassstrom $I_F = f(V_F)$

Forward Current

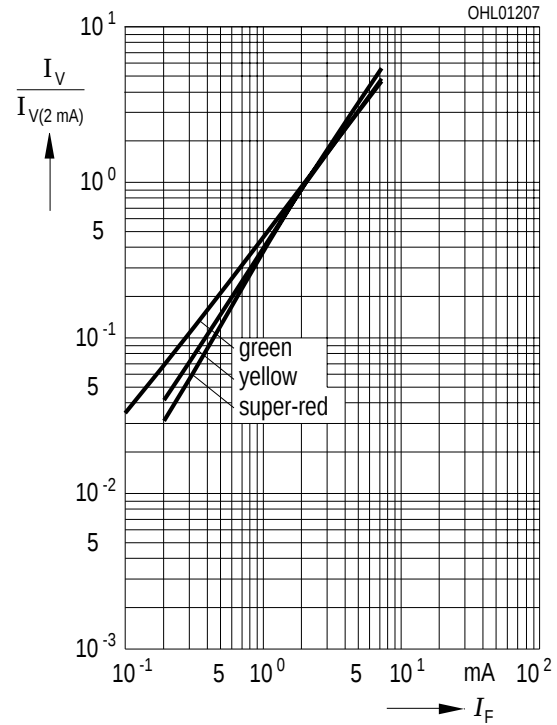
$T_A = 25^\circ\text{C}$



Relative Lichtstärke $I_V/I_{V(2\text{ mA})} = f(I_F)$

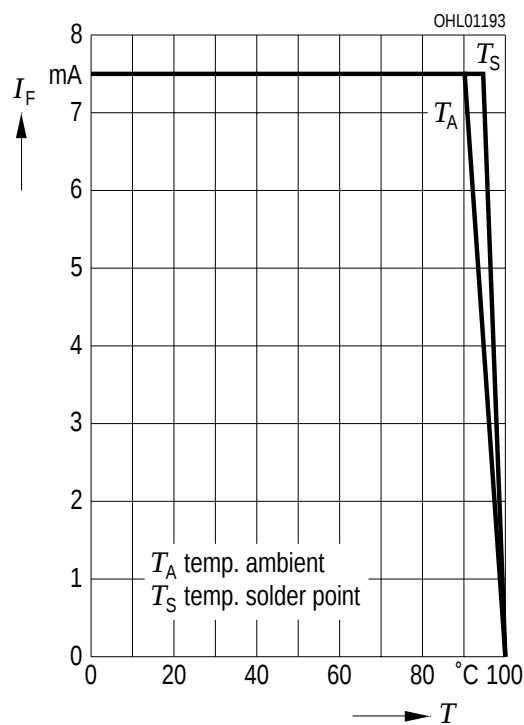
Relative Luminous Intensity

$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$

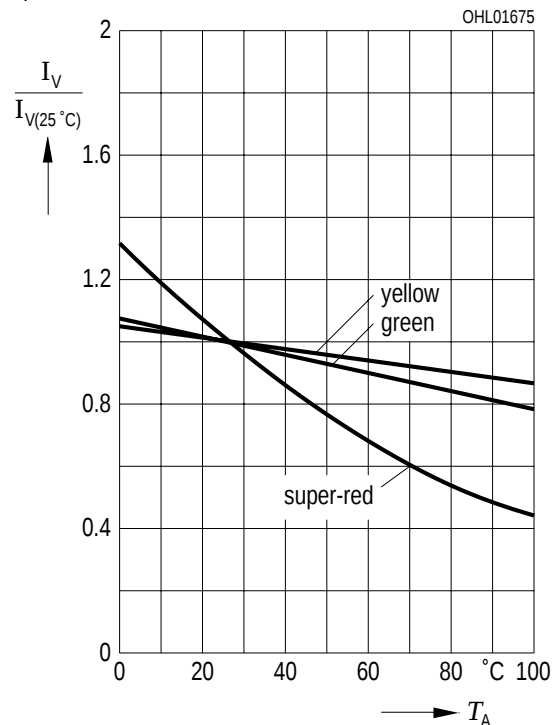
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$

Relative Luminous Intensity

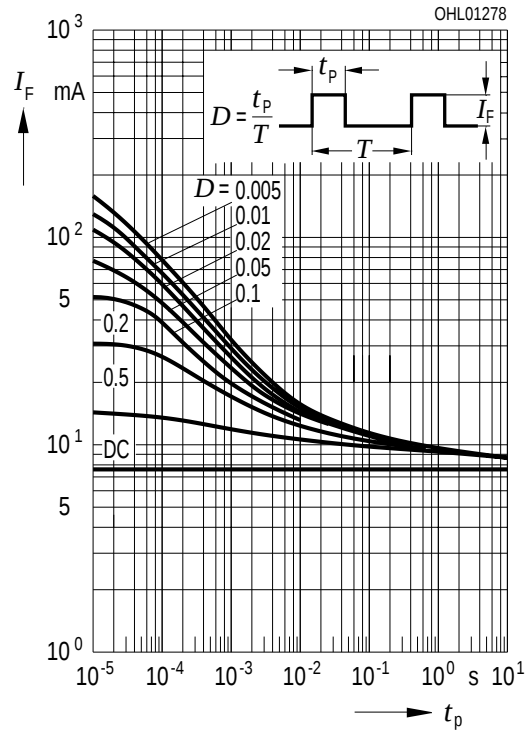
$I_F = 2\text{ mA}$



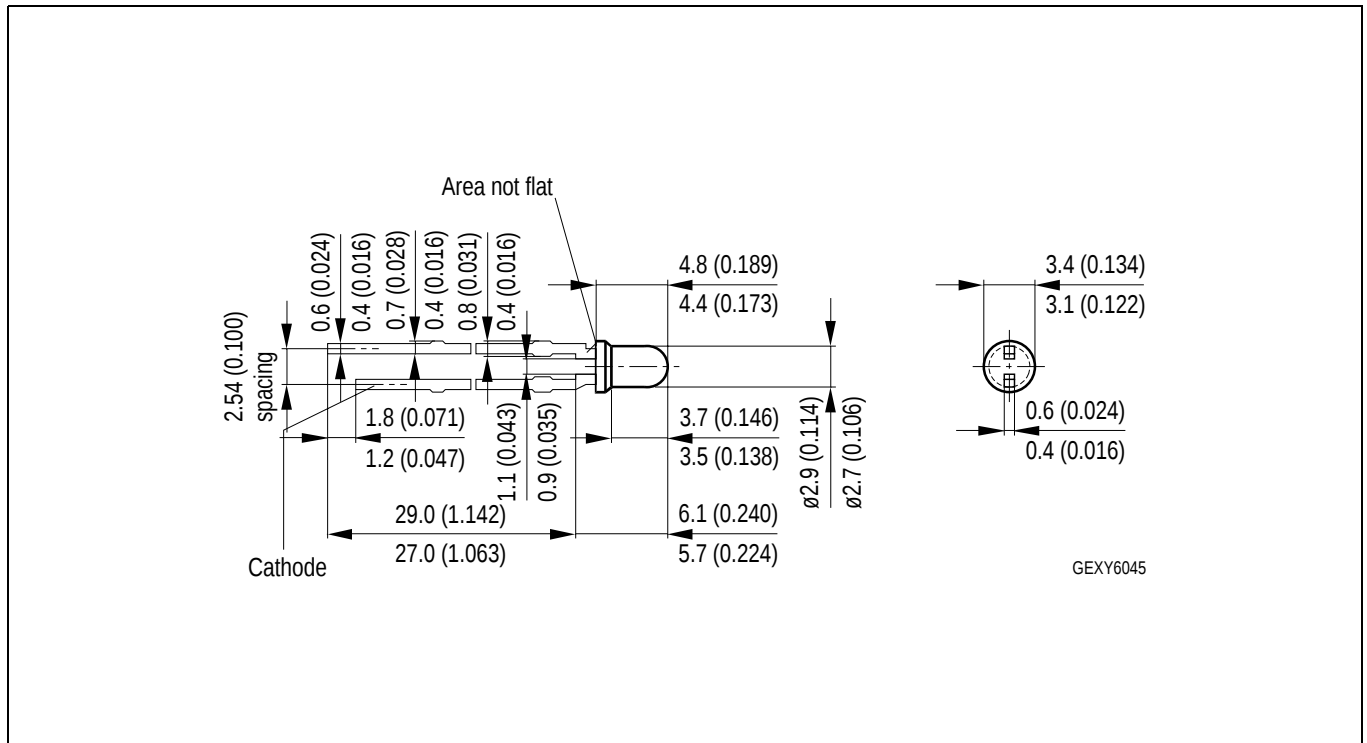
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible Pulse Handling Capability

Duty cycle $D = \text{parameter}$, $T_A = 25\text{ °C}$



Maßzeichnung Package Outlines

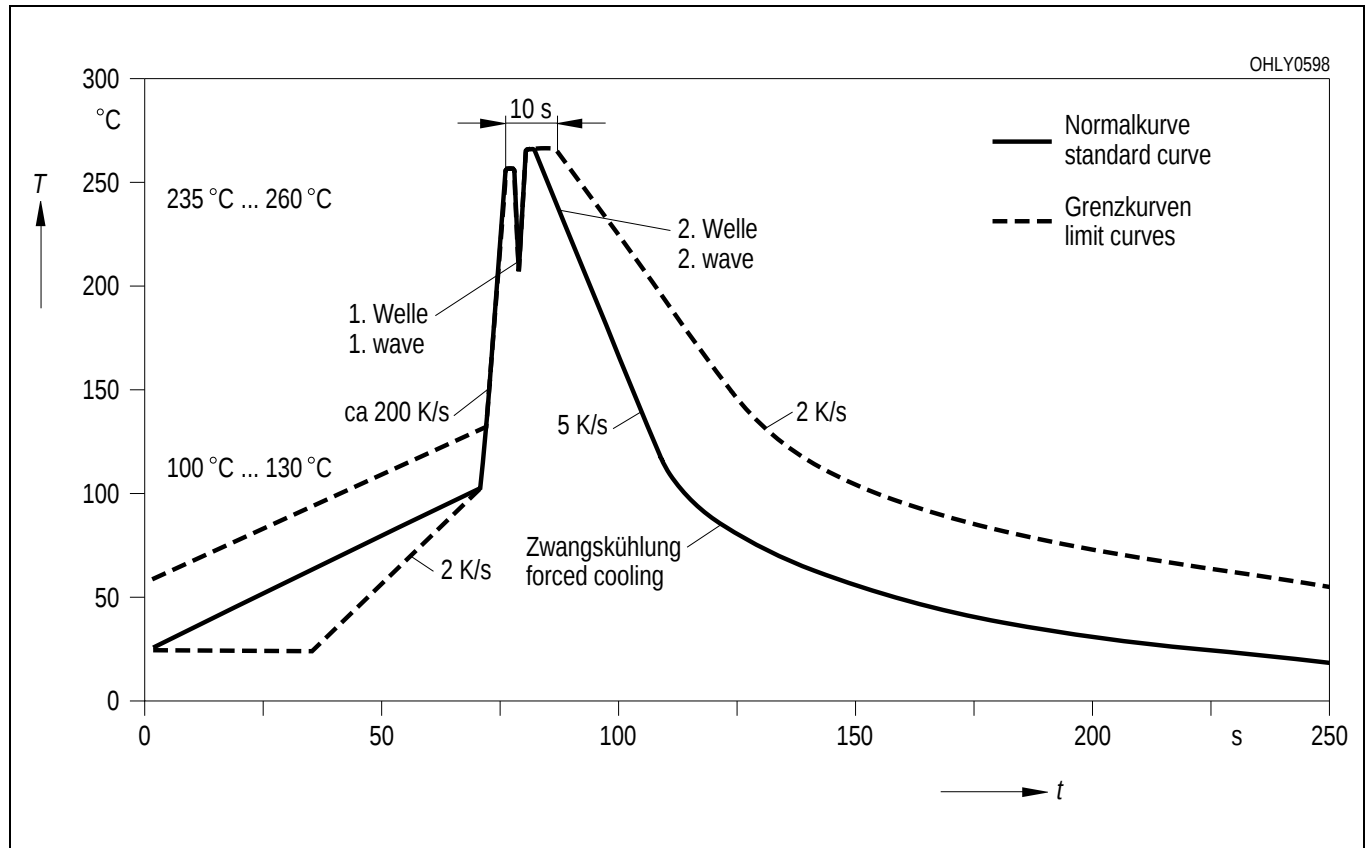


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

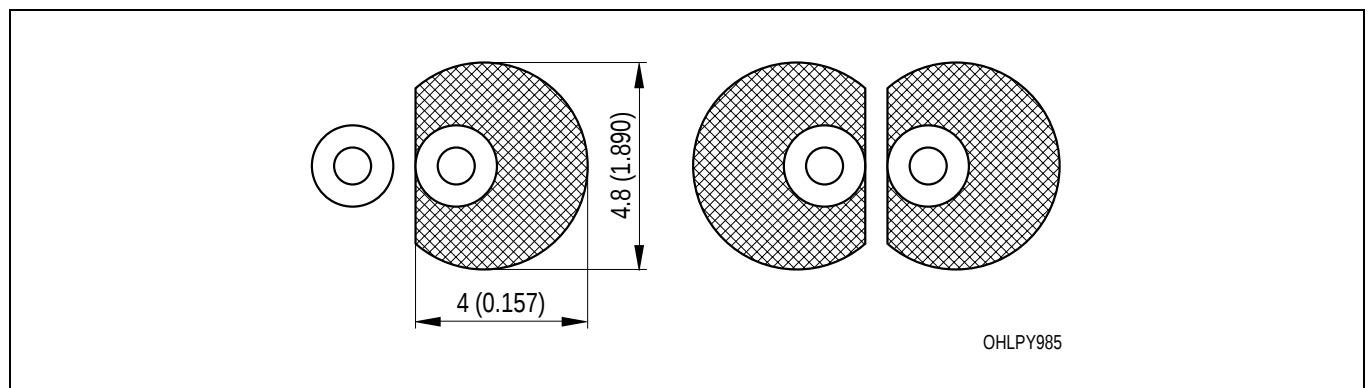
Kathodenkennung: kürzerer Lötspieß
Cathode mark: short solder lead
Gewicht / Approx. weight: 0.15 g

Lötbedingungen Soldering Conditions

Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



Empfohlenes Lötpaddesign Wellenlöten (TTW)
Recommended Solder Pad TTW Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2003-12-19		Date of change
Previous Version: 2003-06-11		
Page	Subjects (major changes since last revision)	
3	thermal resistance (footnote)	
10	annotations	2002-07-23
5	luminous intensity groups	2002-07-30
3, 4	value (reverse voltage from 5 V to 12 V)	2002-09-18
2	not for new design	2002-09-18
2	removal of single brightness groups	2003-06-11
2	removal of not for new design	2003-12-17

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² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.